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<u>Texas Instruments</u> <u>CD74HCT11M96G4</u>

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Data sheet acquired from Harris Semiconductor SCHS273E

August 1997 - Revised September 2003

CD54HC11, CD74HC11, CD54HCT11, CD74HCT11

High-Speed CMOS Logic Triple 3-Input AND Gate

Features

- · Buffered Inputs
- Typical Propagation Delay: 8ns at V_{CC} = 5V, C_L = 15pF, T_A = 25°C
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $\text{I}_{\text{I}} \leq 1 \mu \text{A}$ at $\text{V}_{\text{OL}}, \, \text{V}_{\text{OH}}$

Description

The 'HC11 and 'HCT11 logic gates utilize silicon gate CMOS technology to achieve operating speeds similar to LSTTL gates with the low power consumption of standard CMOS integrated circuits. All devices have the ability to drive 10 LSTTL loads. The HCT logic family is functionally pin compatible with the standard LS logic family.

Ordering Information

PART NUMBER	TEMP. RANGE (^O C)	PACKAGE			
CD54HC11F3A	-55 to 125	14 Ld CERDIP			
CD54HCT11F3A	-55 to 125	14 Ld CERDIP			
CD74HC11E	-55 to 125	14 Ld PDIP			
CD74HC11M	-55 to 125	14 Ld SOIC			
CD74HC11MT	-55 to 125	14 Ld SOIC			
CD74HC11M96	-55 to 125	14 Ld SOIC			
CD74HCT11E	-55 to 125	14 Ld PDIP			
CD74HCT11M	-55 to 125	14 Ld SOIC			
CD74HCT11MT	-55 to 125	14 Ld SOIC			
CD74HCT11M96	-55 to 125	14 Ld SOIC			

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

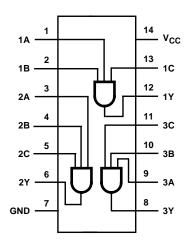
Pinout

CD74HC11, CD74HCT11 (PDIP, SOIC) TOP VIEW 1A 1 14 V_{CC} 1B 2 13 1C 2A 3 12 1Y 11 3C 2B 4 10 3B 2C 5 2Y 6 9 3A 8 3Y GND 7

CD54HC11, CD54HCT11 (CERDIP)



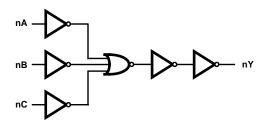
Functional Diagram



TRUTH TABLE

INP	UTS		OUTPUT
nA	nB	nC	nY
L	L	L	L
L	L	Н	L
L	Н	L	L
L	Н	Н	L
Н	L	L	L
Н	L	Н	L
Н	Н	L	L
Н	Н	Н	Н

Logic Symbol





Absolute Maximum Ratings	Thermal Information
DC Supply Voltage, V_{CC} 0.5V to 7V DC Input Diode Current, I_{IK} For $V_I <$ -0.5V or $V_I > V_{CC} + 0.5V$ ± 20 mA DC Output Diode Current, I_{OK} For $V_O <$ -0.5V or $V_O > V_{CC} + 0.5V$ ± 20 mA DC Output Source or Sink Current per Output Pin, I_O For $V_O >$ -0.5V or $V_O < V_{CC} + 0.5V$ ± 25 mA DC V_{CC} or Ground Current, I_{CC} or I_{GND} ± 25 mA	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$
Operating Conditions	
$ \begin{array}{llllllllllllllllllllllllllllllllllll$	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS			25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	.									-	•	
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads		V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage		V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
112 2000			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА



DC Electrical Specifications (Continued)

			ST ITIONS			25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	2	-	20	-	40	μА
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	II	V _{CC} and GND	-	5.5	-		±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	-	5.5	-	-	2	-	20	-	40	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} - 2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
All	0.5

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g. $360\mu A$ max at $25^{o}C.$

Switching Specifications Input t_r , $t_f = 6ns$

		TEST	v _{cc}	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	100	-	125	-	150	ns
Input to Output (Figure 1)			4.5	-	-	20	-	25	-	30	ns
			6	-	-	17	-	21	-	26	ns
Propagation Delay, Data Input to Output Y	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	8	-	1	-	1	-	ns

^{2.} For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.



Switching Specifications Input $t_{\rm f},\ t_{\rm f}$ = 6ns (Continued)

		TEST	v _{cc}		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Transition Times (Figure 1)	t _{TLH} , t _{THL}	C _L = 50pF	2	ı	ı	75	-	95	-	110	ns
			4.5	ı	ı	15	ı	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	Cl	C _L = 50pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	C _L = 15pF	5	-	26	-	-	-	-	-	pF
HCT TYPES		•									
Propagation Delay, Input to Output (Figure 2)	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	28	-	35	-	42	ns
Propagation Delay, Data Input to Output Y	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	11	-	-	-	-	-	ns
Transition Times (Figure 2)	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C _I	C _L = 50pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	28	1	1	-	-	-	pF

NOTES:

- 3. $C_{\mbox{PD}}$ is used to determine the dynamic power consumption, per gate.
- 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_I)$ where f_i = input frequency, C_I = output load capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms

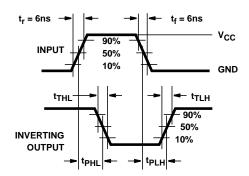


FIGURE 1. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

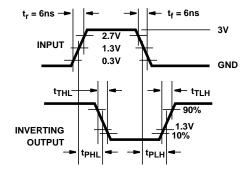


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



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PACKAGE OPTION ADDENDUM

10-Jun-2014

PACKAGING INFORMATION

Lead/Ball Finish MSL Peak Temp Orderable Device Status Package Type Package Pins Package Eco Plan Op Temp (°C) Device Marking Samples Qty Drawing (2) (6) (3) 5962-8970901CA ACTIVE CDIF TBD 5962-8970901CA 14 A42 N / A for Pkg Type -55 to 125 Samples CD54HCT11F3A CD54HC11F ACTIVE 1 A42 CD54HC11F CDIF J 14 TBD N / A for Pkg Type -55 to 125 Samples CD54HC11F3A ACTIVE CDIP 14 TBD A42 N / A for Pkg Type -55 to 125 8404801CA J 1 Samples CD54HC11F3A CD54HCT11F ACTIVE CDIP TBD A42 N / A for Pkg Type CD54HCT11F 14 Samples CD54HCT11F3A A42 ACTIVE CDIF 14 N / A for Pkg Type -55 to 125 5962-8970901CA Samples CD54HCT11F3A CD74HC11E ACTIVE PDIP 25 CU NIPDAU N / A for Pkg Type CD74HC11E 14 Samples (RoHS) CD74HC11EE4 ACTIVE PDIP Ν 14 25 Pb-Free CU NIPDAU N / A for Pkg Type -55 to 125 CD74HC11E Samples (RoHS) CD74HC11M ACTIVE SOIC D 14 50 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -55 to 125 HC11M Samples & no Sb/Br) CD74HC11M96 ACTIVE SOIC D 14 2500 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -55 to 125 HC11M Samples & no Sb/Br) CD74HC11M96G4 ACTIVE SOIC D 14 2500 Green (RoHS **CU NIPDAU** Level-1-260C-UNLIM -55 to 125 HC11M Samples & no Sb/Br) CD74HC11MG4 ACTIVE SOIC D 14 50 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -55 to 125 HC11M Samples & no Sb/Br) CD74HC11MT CU NIPDAU Level-1-260C-UNLIM HC11M **ACTIVE** SOIC D 14 250 Green (RoHS -55 to 125 Samples & no Sb/Br) CD74HCT11E CU NIPDAU CD74HCT11E ACTIVE PDIP Ν 14 25 Pb-Free N / A for Pkg Type -55 to 125 Samples (RoHS) CD74HCT11M ACTIVE CU NIPDAU HCT11M SOIC D Level-1-260C-UNLIM -55 to 125 14 50 Green (RoHS Samples & no Sb/Br) CU NIPDAU CD74HCT11M96 ACTIVE SOIC Green (RoHS HCT11M D 14 2500 Level-1-260C-UNLIM -55 to 125 Samples & no Sb/Br) CD74HCT11M96E4 ACTIVE SOIC D CU NIPDAU Level-1-260C-UNLIM HCT11M 14 2500 Green (RoHS -55 to 125 & no Sb/Br) CD74HCT11M96G4 ACTIVE D 14 2500 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -55 to 125

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& no Sb/Br)



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PACKAGE OPTION ADDENDUM

10-Jun-2014

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT11MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT11M	Samples
CD74HCT11MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT11M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Ti's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(6) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish

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PACKAGE OPTION ADDENDUM

www.ti.com 10-Jun-2014

OTHER QUALIFIED VERSIONS OF CD54HC1	1, CD54HCT11, CD74HC11, CD74HCT11:
-------------------------------------	------------------------------------

- Catalog: CD74HC11, CD74HCT11
- Military: CD54HC11, CD54HCT11

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

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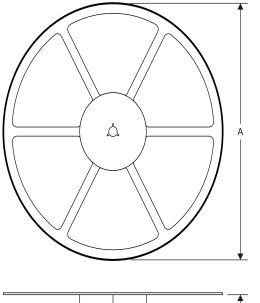


PACKAGE MATERIALS INFORMATION

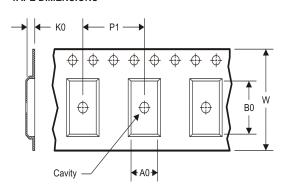
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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers



TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC11M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC11MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT11M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT11MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

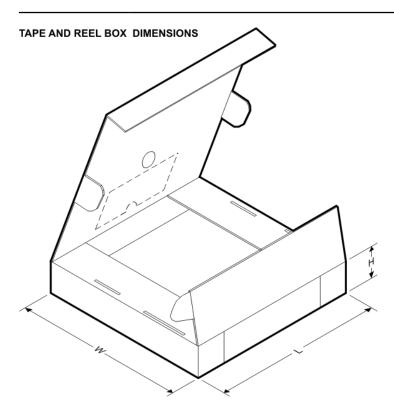
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PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

7 til dillionolorio dio nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC11M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HC11MT	SOIC	D	14	250	367.0	367.0	38.0
CD74HCT11M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HCT11MT	SOIC	D	14	250	367.0	367.0	38.0

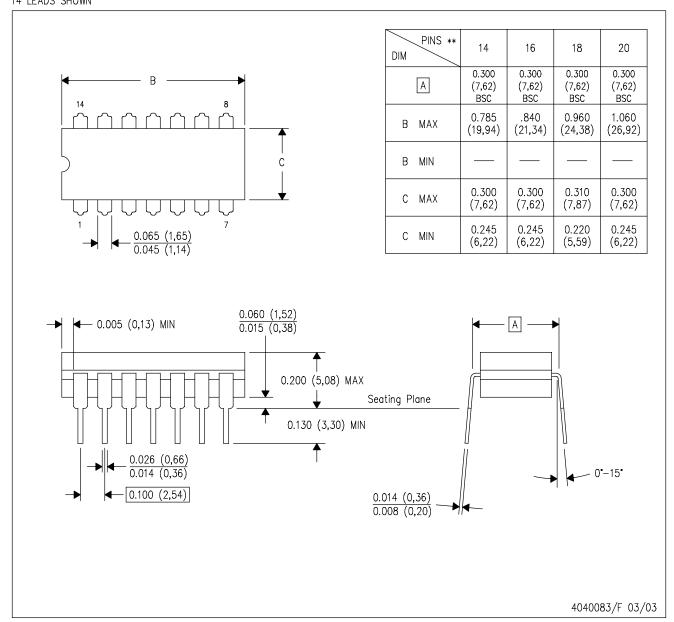
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J (R-GDIP-T**)

CERAMIC DUAL IN-LINE PACKAGE

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

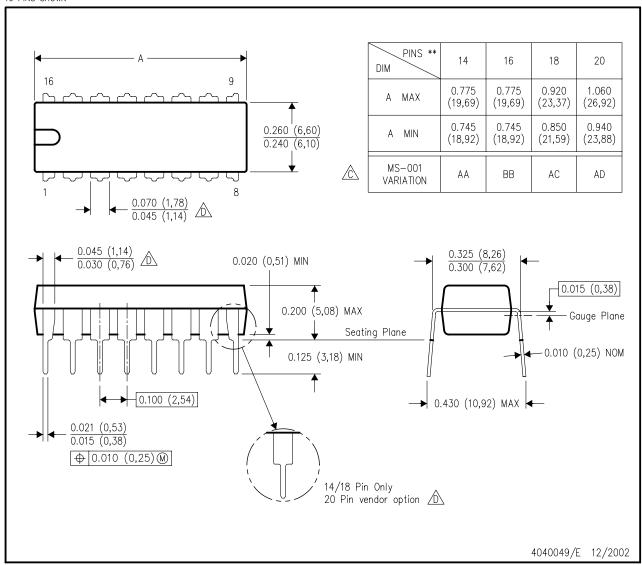


MECHANICAL DATA

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- . All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.

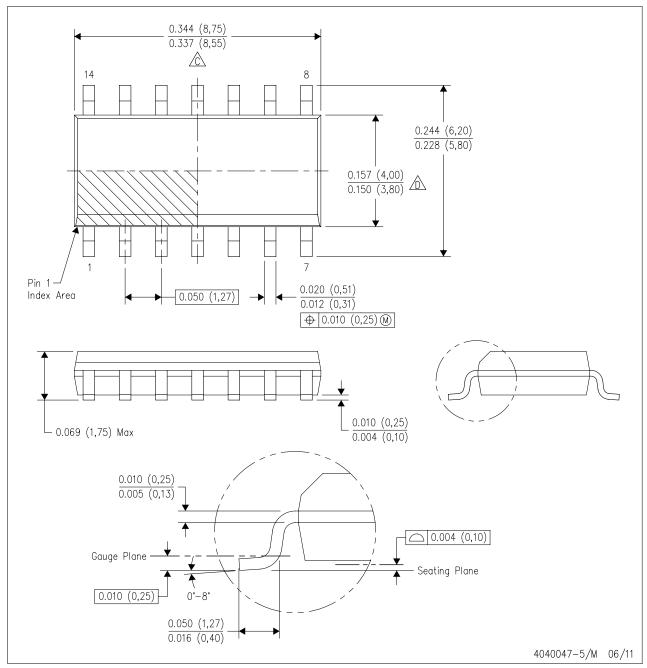




MECHANICAL DATA

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



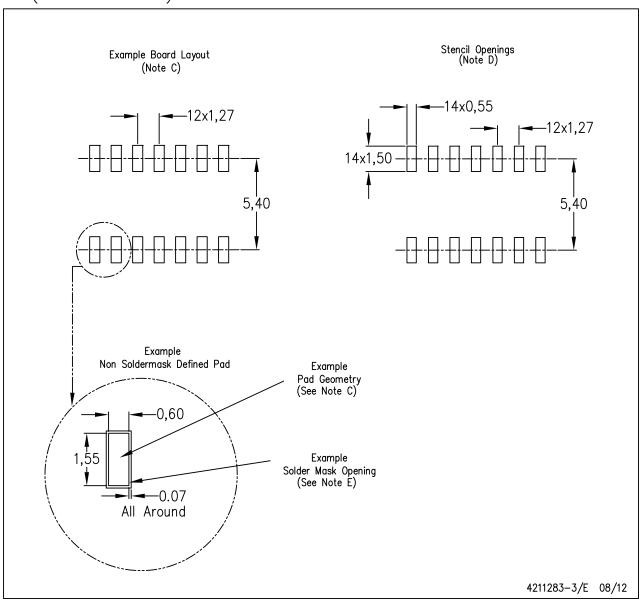




LAND PATTERN DATA

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





Datasheet of CD74HCT11M96G4 - IC GATE AND 3CH 3-INP 14-SOIC

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